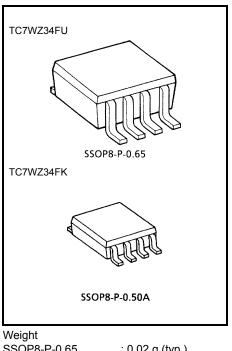
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WZ34FU,TC7WZ34FK

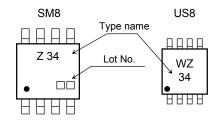
**Triple NON-Inverter** 

#### Features

- High output drive:  $\pm 24$  mA (min) at V<sub>CC</sub> = 3 V
- Super high speed operation: t<sub>pd</sub> = 2.4 ns (typ.)
  - at V<sub>CC</sub> = 5 V, 50 pF
- Operation voltage range: V<sub>CC (opr)</sub> = 1.65~5.5 V
- 5.5-V tolerant inputs
- 5.5-V power down protection outputs
- Matches the performance of TC74LCX series when operated at 3.3-V  $V_{CC}$



#### Marking



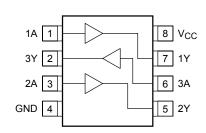


: 0.02 g (typ.) : 0.01 g (typ.)

# Maximum Ratings (Ta = 25°C)

| Characteristics                    | Symbol           | Rating                 | Unit |  |
|------------------------------------|------------------|------------------------|------|--|
| Power supply voltage               | V <sub>CC</sub>  | -0.5~6                 | V    |  |
| DC input voltage                   | V <sub>IN</sub>  | -0.5~6                 | V    |  |
| DC output voltage                  | Vout             | -0.5~6                 | V    |  |
| Input diode current                | I <sub>IK</sub>  | -20                    | mA   |  |
| Output diode current               | IOK              | -20                    | mA   |  |
| DC output current                  | IOUT             | ±50                    | mA   |  |
| DC V <sub>CC</sub> /ground current | ICC              | ±50                    | mA   |  |
| Power dissipation                  | PD               | 300 (SM8)<br>200 (US8) | mW   |  |
| Storage temperature                | T <sub>stg</sub> | -65~150                | °C   |  |
| Lead temperature (10s)             | TL               | 260                    | °C   |  |

Pin Assignment (top view)

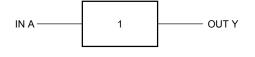


# <u>TOSHIBA</u>

#### **Truth Table**

Logic Diagram

| А | Y |
|---|---|
| L | L |
| Н | Н |



### **Recommended Operating Conditions**

| Characteristics          | Symbol                         | Rating  | Unit |  |
|--------------------------|--------------------------------|---|------|--|
| Supply voltage           | Vcc                            | 1.65~5.5  | V    |  |
| Supply voltage           | VCC                            | 1.5~5.5 (Note 1)                                      | v    |  |
| Input voltage            | V <sub>IN</sub>                | 0~5.5   | V    |  |
| Output voltage           | V <sub>OUT</sub>               | 0~5.5 (Note 2)  | V    |  |
|                          |                                | 0~V <sub>CC</sub> (Note 3)                            | v    |  |
| Operating temperature    | T <sub>opr</sub>               | -40~85  | °C   |  |
|                          | d <sub>t</sub> /d <sub>v</sub> | 0~20 (V_{CC} = 1.8 V $\pm$ 0.15 V, 2.5 V $\pm$ 0.2 V) | ns/V |  |
| Input rise and fall time |                                | 0~10 (V_{CC} = 3.3 V $\pm$ 0.3 V)                     |      |  |
|                          |                                | 0~5 (V_{CC} = 5.5 V $\pm$ 0.5 V)                      |      |  |

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state

## **Electrical Characteristics**

#### **DC Characteristics**

| Characteristics Symbol |                 | Symbol Test Condition     |                                    |  | Ta = 25°C              |                          |                           | Ta = -40~85°C          |   | Unit                    |     |
|------------------------|-----------------|---------------------------|------------------------------------|--|------------------------|--------------------------|---------------------------|------------------------|---|-------------------------|-----|
|                        |                 |                           |                                    | V <sub>CC</sub> (V)  | Min                    | Тур.                     | Max                       | Min                    | Max   | Unit                    |     |
| High level             |                 | Mari                      |                                    |  | 1.65~<br>1.95          | $_{\timesV_{CC}}^{0.75}$ | _                         | _                      | $\begin{array}{c} 0.75 \\ \times  V_{CC} \end{array}$ | _                       | - V |
| Input<br>voltage       | V <sub>IH</sub> | —                         |                                    | 2.3~5.5  | $0.7 \\ \times V_{CC}$ | _                        | _                         | $0.7 \\ \times V_{CC}$ | _   |                         |     |
|                        |                 |                           |                                    | 1.65~<br>1.95  | _                      |                          | 0.25<br>× V <sub>CC</sub> | _                      | $\begin{array}{c} 0.25 \\ \times  V_{CC} \end{array}$ |                         |     |
|                        | Low level       | V <sub>IL</sub>           |                                    |  | 2.3~5.5                | _                        | —                         | $0.3 \times V_{CC}$    |   | $0.3 \\ \times  V_{CC}$ |     |
|                        |                 |                           |                                    |  | 1.65                   | 1.55                     | 1.65                      | _                      | 1.55  |                         |     |
|                        |                 |                           |                                    | I <sub>OH</sub> = -100 μA  | 2.3                    | 2.2                      | 2.3                       | —                      | 2.2   | —                       |     |
|                        |                 |                           |                                    | 10H - 100 m/   | 3.0                    | 2.9                      | 3.0                       | —                      | 2.9   |                         |     |
|                        |                 |                           |                                    |  | 4.5                    | 4.4                      | 4.5                       | —                      | 4.4   | —                       |     |
|                        | High level      | V <sub>OH</sub>           | $V_{IN} = V_{IH}$                  | $I_{OH} = -4 \text{ mA}$   | 1.65                   | 1.29                     | 1.52                      | —                      | 1.29  |                         |     |
|                        |                 |                           |                                    | I <sub>OH</sub> = -8 mA  | 2.3                    | 1.9                      | 2.15                      | —                      | 1.9   | —                       |     |
|                        |                 |                           |                                    | $I_{OH} = -16 \text{ mA}$  | 3.0                    | 2.4                      | 2.8                       | _                      | 2.4   | —                       |     |
|                        |                 |                           |                                    | $I_{OH} = -24 \text{ mA}$  | 3.0                    | 2.3                      | 2.68                      |                        | 2.3   | —                       |     |
| Output                 |                 |                           |                                    | I <sub>OH</sub> = -32 mA   | 4.5                    | 3.8                      | 4.2                       | _                      | 3.8   | —                       | V   |
| voltage                |                 | .ow level V <sub>OL</sub> | VIN = VIL                          | $I_{OL} = 100 \ \mu A$<br>$I_{OL} = 4 \ m A$<br>$I_{OL} = 8 \ m A$ | 1.65                   | —                        | 0                         | 0.1                    | _   | 0.1                     | v   |
|                        |                 |                           |                                    |  | 2.3                    | —                        | 0                         | 0.1                    | _   | 0.1                     |     |
|                        |                 |                           |                                    |  | 3.0                    | —                        | 0                         | 0.1                    | _   | 0.1                     | -   |
|                        |                 |                           |                                    |  | 4.5                    | —                        | 0                         | 0.1                    | _   | 0.1                     |     |
| Low leve               | Low level       |                           |                                    |  | 1.65                   | —                        | 0.08                      | 0.24                   | _   | 0.24                    |     |
|                        |                 |                           |                                    |  | 2.3                    | —                        | 0.1                       | 0.3                    | _   | 0.3                     |     |
|                        |                 |                           |                                    | $I_{OL} = 16 \text{ mA}$   | 3.0                    | —                        | 0.15                      | 0.4                    | _   | 0.4                     |     |
|                        |                 |                           |                                    | $I_{OL} = 24 \text{ mA}$   | 3.0                    | —                        | 0.22                      | 0.55                   | —   | 0.55                    |     |
|                        |                 |                           |                                    | $I_{OL} = 32 \text{ mA}$   | 4.5                    | —                        | 0.22                      | 0.55                   | _   | 0.55                    |     |
| Input leakage          |                 | I <sub>IN</sub>           | $V_{IN} = 5.5 V$                   | or GND   | 0~5.5                  | —                        |                           | ±1                     | —   | ±10                     | μA  |
| Power off lea          | kage current    | IOFF                      | $V_{\text{IN}}$ or $V_{\text{OL}}$ | JT = 5.5 V   | 0.0                    | —                        | _                         | 1                      | _   | 10                      | μA  |
| Quiescent su           | pply current    | ICC                       | $V_{IN} = 5.5 \ V$                 | or GND   | 1.65~5.5               | —                        | —                         | 1                      | —   | 10                      | μA  |

#### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$ )

| Characteristics               | Symbol                               | Test Condition                                  |                               | Ta = 25°C |      |     | Ta = -40~85°C |      | Unit |
|-------------------------------|--------------------------------------|---|-------------------------------|-----------|------|-----|---------------|------|------|
| Characteristics               | Symbol                               | Test Condition                                  | V <sub>CC</sub> (V)           | Min       | Тур. | Max | Min           | Max  | Unit |
| Propagation delay time        | <sup>t</sup> pLH<br>t <sub>pHL</sub> | $C_L$ = 15 pF, $R_L$ = 1 M $\Omega$             | $1.8\pm0.15$                  | 2.0       | 4.4  | 9.5 | 2.0           | 10.0 | - ns |
|                               |                                      |   | $2.5\pm0.2$                   | 1.0       | 3.0  | 5.2 | 1.0           | 5.8  |      |
|                               |                                      |   | $\textbf{3.3}\pm\textbf{0.3}$ | 0.8       | 2.3  | 3.6 | 0.8           | 4.0  |      |
|                               |                                      |   | $5.0\pm0.5$                   | 0.5       | 1.8  | 2.9 | 0.5           | 3.2  |      |
|                               |                                      | $C_L = 50 \text{ pF}, \text{ R}_L = 500 \Omega$ | $\textbf{3.3}\pm\textbf{0.3}$ | 1.2       | 3.0  | 4.6 | 1.2           | 5.1  |      |
|                               |                                      |   | $5.0\pm0.5$                   | 0.8       | 2.4  | 3.8 | 0.8           | 4.2  |      |
| Input capacitance             | CIN                                  | —   | 0~5.5                         | _         | 3.0  | _   | _             | _    | pF   |
| Power dissipation capacitance | C <sub>PD</sub> (Note                | (Note 4)  | 3.3                           |           | 24   | _   |               |      | pF   |
|                               |                                      | (Note 4)  | 5.5                           | _         | 34   | _   |               |      | μr   |

Note 4: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

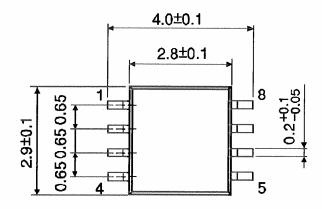
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ 

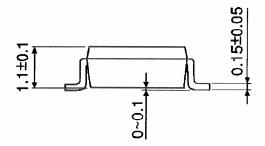
# TOSHIBA

## Package Dimensions

SSOP8-P-0.65

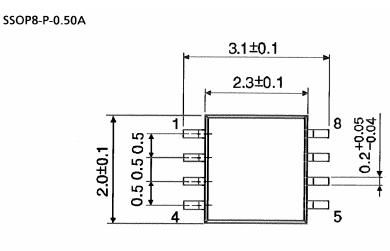
Unit : mm

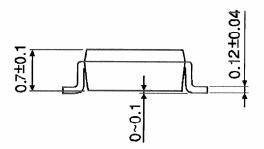




Weight: 0.02 g (typ.)

# Package Dimensions





Weight: 0.01 g (typ.)

Downloaded from Elcodis.com electronic components distributor

Unit : mm

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